



500mA CMOS LDO Regulator

FEATURES

- Guaranteed 500mA peak output current
- Low dropout voltage of 300mV typical at 500mA
- Stable with ceramic output capacitor
- External 10nF bypass capacitor for low noise
- Quick-start feature
- Under voltage lockout
- No-load ground current of 55µA typical
- Full-load ground current of 85µA typical
- ±1.0% output voltage initial accuracy
- ±2.0% accuracy over temperature
- “Zero” current shutdown mode
- Current limit and thermal protection
- 5-lead thin SOT-23 and 6-lead TDFN packages

APPLICATIONS

- Cellular phones
- Battery-powered devices
- Consumer Electronics

DESCRIPTION

The CAT6219 is a 500mA CMOS low dropout regulator that provides fast response time during load current and line voltage changes.

The quick-start feature allows the use of an external bypass capacitor to reduce the overall output noise without affecting the turn-on time of just 150µs.

With zero shutdown current and low ground current of 55µA typical, the CAT6219 is ideal for battery-operated devices with supply voltages from 2.3V to 5.5V. An internal under voltage lockout circuit disables the output at supply voltages under 2.15V typical.

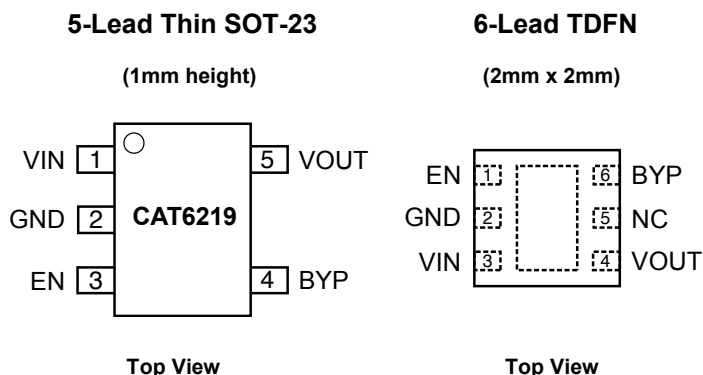
The CAT6219 offers 1% initial accuracy and low dropout voltage, 300mV typical at 500mA. Stable operation is provided with a small value ceramic capacitor, reducing required board space and component cost.

Other features include current limit and thermal protection.

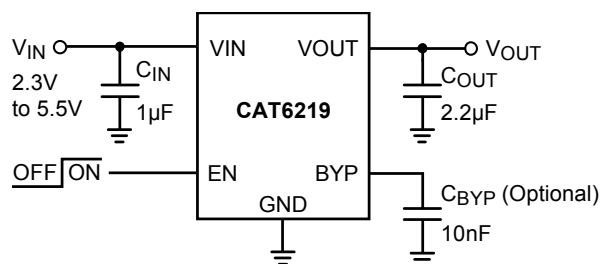
The device is available in the low profile (1mm max height) 5-lead thin SOT23 and in the 6-lead 2mm x 2mm TDFN packages.

For Ordering Information details, see page 9.

PIN CONFIGURATION



TYPICAL APPLICATION CIRCUIT



PIN DESCRIPTIONS

Pin #	Name	Function
1	VIN	Supply voltage input.
2	GND	Ground reference.
3	EN	Enable input (active high); a 2.5MΩ pull-down resistor is provided.
4	BYP	Optional bypass capacitor connection for noise reduction and PSRR enhancing.
5	VOUT	LDO Output Voltage.

BLOCK DIAGRAM

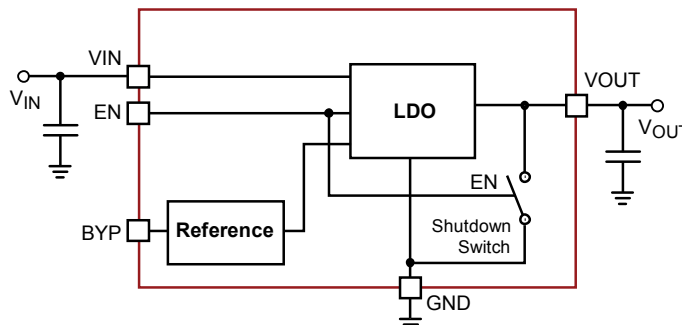


Figure 2. CAT6219 Functional Block Diagram

PIN FUNCTION

VIN is the supply pin for the LDO. A small 1μF ceramic bypass capacitor is required between the V_{IN} pin and ground near the device. When using longer connections to the power supply, C_{IN} value can be increased without limit. The operating input voltage range is from 2.3V to 5.5V.

EN is the enable control logic (active high) for the regulator output. It has a 2.5MΩ pull-down resistor, which assures that if EN pin is left open, the circuit is disabled.

VOUT is the LDO regulator output. A small 2.2μF ceramic bypass capacitor is required between the VOUT pin and ground. For better transient response, its value can be increased to 4.7μF.

The capacitor should be located near the device. For the SOT23-5 package, a continuous 500mA output current may turn-on the thermal protection. A 250Ω internal shutdown switch discharges the output capacitor in the no-load condition.

GND is the ground reference for the LDO. The pin must be connected to the ground plane on the PCB.

BYP is the reference bypass pin. An optional 0.01μF capacitor can be connected between BYP pin and GND to reduce the output noise and enhance the PSRR at high frequency.

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Parameter	Rating	Unit
V _{IN}	0 to 6.5	V
V _{EN} , V _{OUT}	-0.3 to V _{IN} +0.3	V
Junction Temperature, T _J	+150	°C
Power Dissipation, P _D	Internally Limited ⁽²⁾	mW
Storage Temperature Range, T _S	-65 to +150	°C
Lead Temperature (soldering, 5 sec.)	260	°C
ESD Rating (Human Body Model)	3	kV

RECOMMENDED OPERATING CONDITIONS ⁽³⁾

Parameter	Range	Unit
V _{IN}	2.3 to 5.5	V
V _{EN}	0 to V _{IN}	V
Junction Temperature Range, T _J	-40 to +125	°C
Package Thermal Resistance (SOT23-5), θ _{JA}	235	°C/W

Typical application circuit with external components is shown on page 1.

Notes:

- (1) Exceeding maximum rating may damage the device.
- (2) The maximum allowable power dissipation at any T_A (ambient temperature) is P_{Dmax} = (T_{Jmax} - T_A) / θ_{JA}. Exceeding the maximum allowable power dissipation will result in excessive die temperature, and the regulator will go into thermal shutdown.
- (3) The device is not guaranteed to work outside its operating rating.

ELECTRICAL OPERATING CHARACTERISTICS ⁽¹⁾

$V_{IN} = V_{OUT} + 1.0V$, $V_{EN} = \text{High}$, $I_{OUT} = 100\mu A$, $C_{IN} = 1\mu F$, $C_{OUT} = 2.2\mu F$, ambient temperature of 25°C (over recommended operating conditions unless specified otherwise). **Bold numbers** apply for the entire junction temperature range.

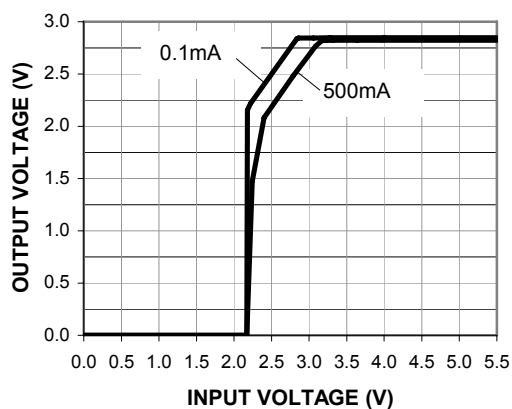
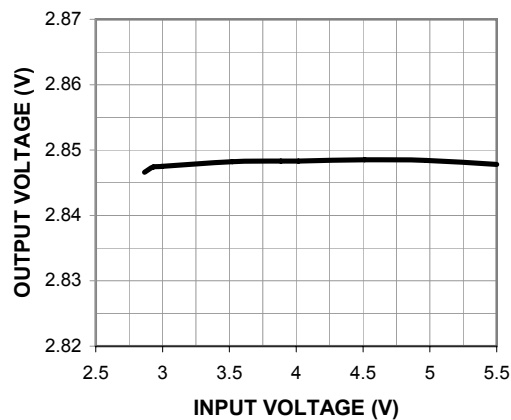
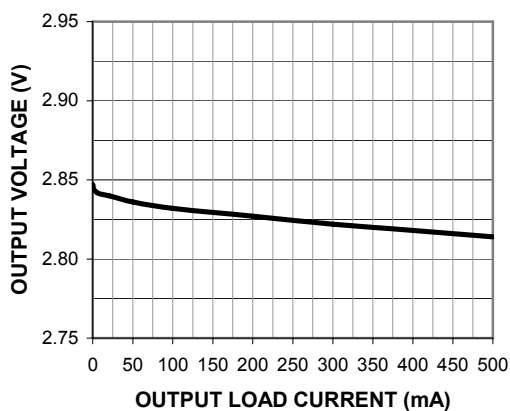
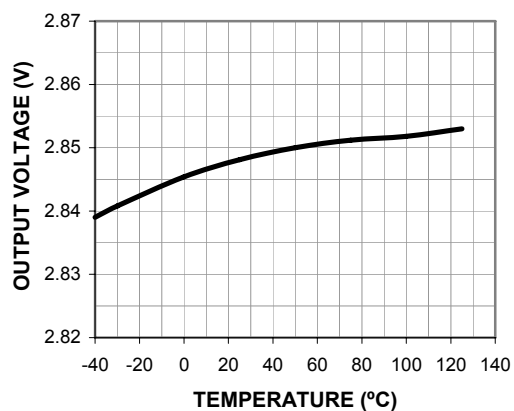
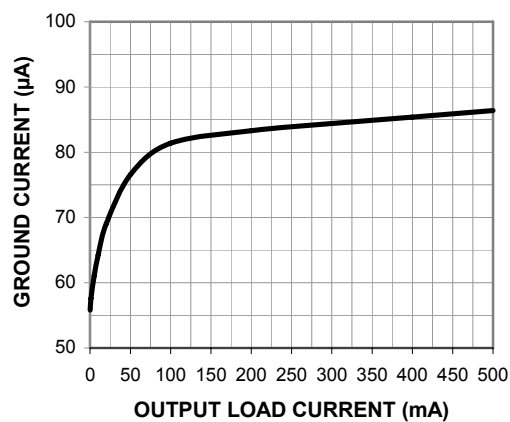
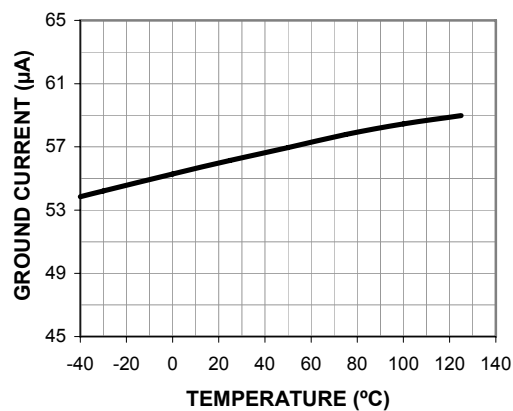
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{OUT-ACC}	Output Voltage Accuracy	Initial accuracy	-1.0		+1.0	%
			-2.0		+2.0	
TC _{OUT}	Output Voltage Temp. Coefficient			40		ppm/°C
V _{R-LINE}	Line Regulation	V _{IN} = V _{OUT} + 1.0V to 5.5V	-0.2	±0.1	+0.2	%/V
			-0.4		+0.4	
V _{R-LOAD}	Load Regulation	I _{OUT} = 100μA to 500 mA		1	1.5	%
					2	
V _{DROP}	Dropout Voltage ⁽²⁾	I _{OUT} = 500mA		300	400	mV
					500	
I _{GND}	Ground Current	I _{OUT} = 0μA		55	75	μA
					90	
		I _{OUT} = 500mA		85		
I _{GND-SD}	Shutdown Ground Current	V _{EN} < 0.4V			1	μA
					2	
PSRR	Power Supply Rejection Ratio	f = 1kHz, C _{BYP} = 10nF		64		dB
		f = 20kHz, C _{BYP} = 10nF		54		
I _{SC}	Output short circuit current limit	V _{OUT} = 0V	600	800		mA
T _{ON}	Turn-On Time	C _{BYP} = 10nF		150		μs
e _N	Output Noise Voltage ⁽³⁾	BW = 10Hz to 100kHz		45		μVrms
R _{OUT-SH}	Shutdown Switch Resistance			250		Ω
R _{EN}	Enable pull-down resistor			2.5		MΩ
V _{IN-UVLO}	Under voltage lockout threshold			2.15		V
ESR	C _{OUT} equivalent series resistance		5		500	mΩ
Enable Input						
V _{HI}	Logic High Level	V _{IN} = 2.3 to 5.5V	1.8			V
V _{LO}	Logic Low Level	V _{IN} = 2.3 to 5.5V			0.4	V
I _{EN}	Enable Input Current	V _{EN} = 0.4V		0.15	1	μA
		V _{EN} = V _{IN}		1.5	4	
Thermal Protection						
T _{SD}	Thermal Shutdown			160		°C
T _{HYS}	Thermal Hysteresis			10		°C

Notes:

- (1) Specification for 2.85V output version unless specified otherwise.
- (2) Dropout voltage is defined as the input-to-output differential at which the output voltage drops 2% below its nominal value measured at 1V differential. During test, the input voltage stays always above the minimum 2.3V.
- (3) Specification for 1.8V output version.

TYPICAL CHARACTERISTICS (shown for 2.85V output version)

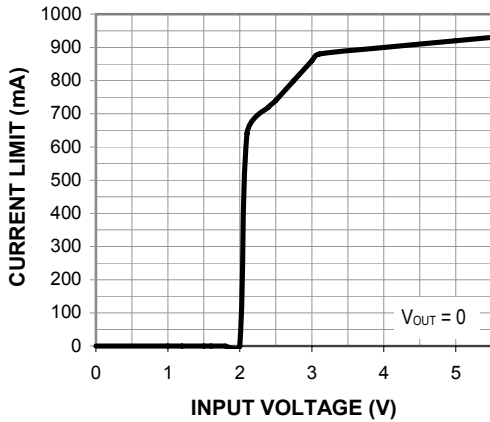
 $V_{IN} = 3.85V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1\mu F$, $C_{OUT} = 2.2\mu F$, $C_{BYP} = 10nF$, $T_A = 25^\circ C$ unless otherwise specified.

Dropout Characteristics

Line Regulation

Load Regulation

Output Voltage vs. Temperature

Ground Current vs. Load Current

Ground Current vs. Temperature


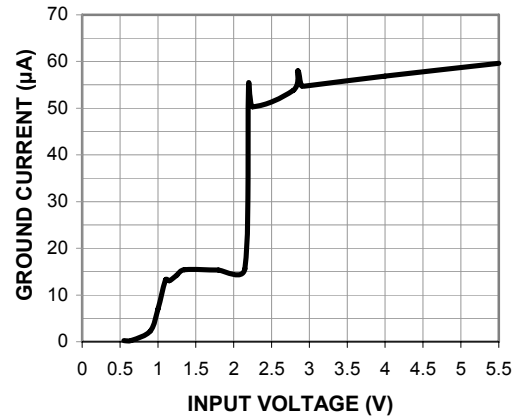
TYPICAL CHARACTERISTICS (shown for 2.85V output option)

$V_{IN} = 3.85V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1\mu F$, $C_{OUT} = 2.2\mu F$, $C_{BYP} = 10nF$, $T_A = 25^\circ C$ unless otherwise specified.

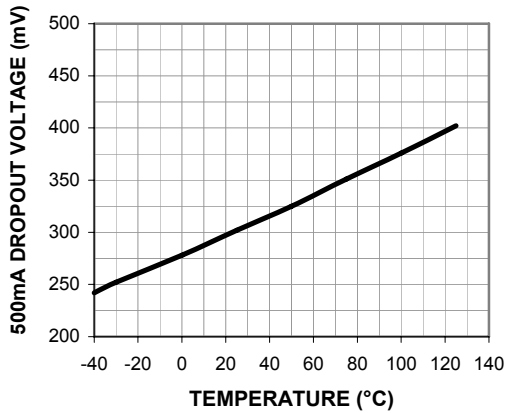
Output Short-circuit Current vs. Input Voltage



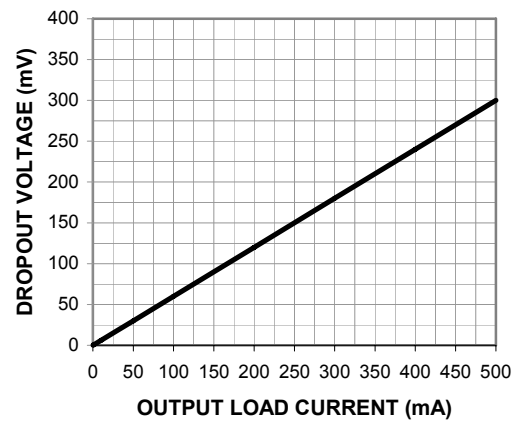
Ground Current vs. Input Voltage



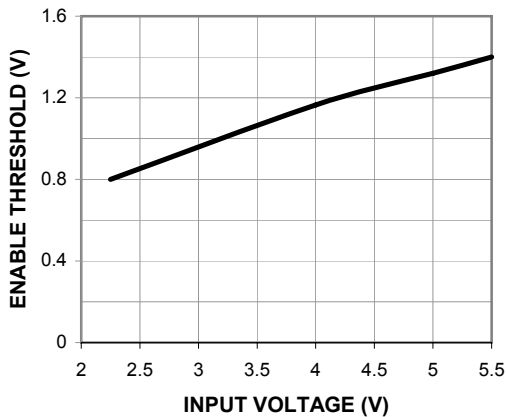
Dropout vs. Temperature (500mA Load)



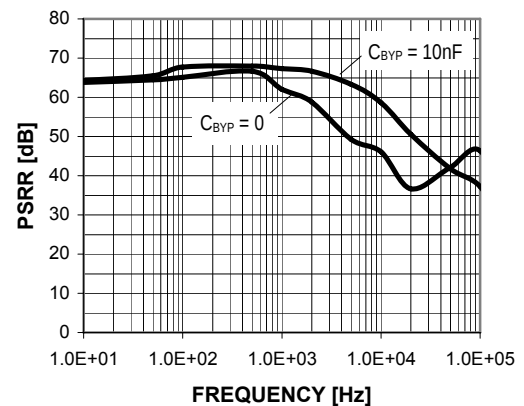
Dropout vs. Load Current



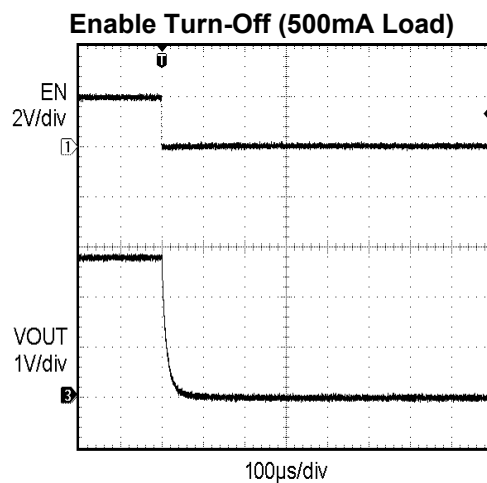
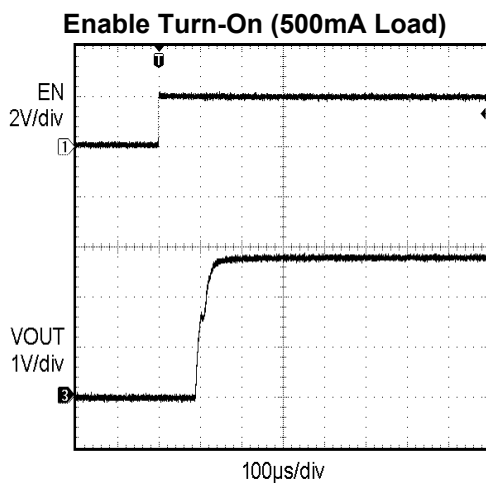
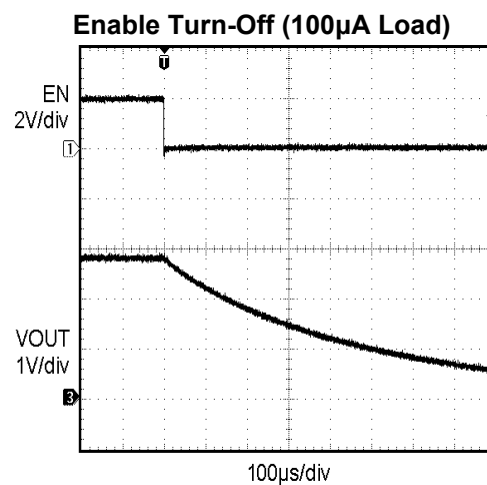
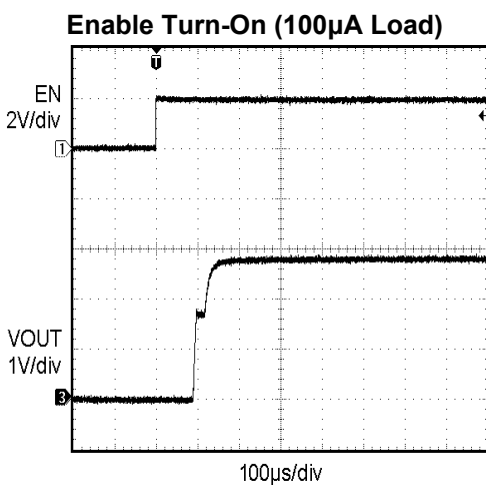
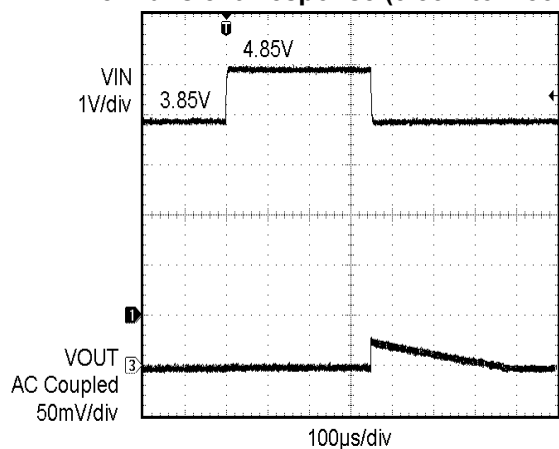
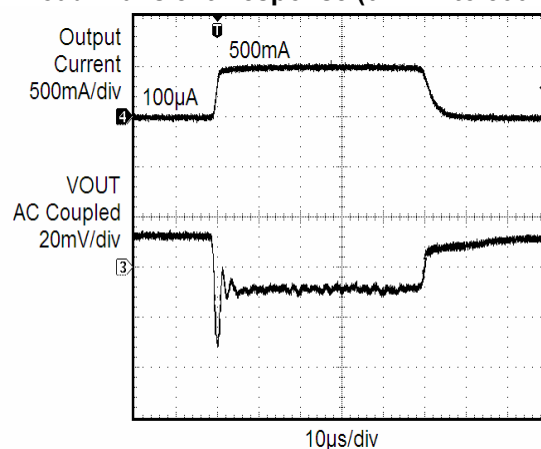
Enable Threshold vs. Input Voltage



PSRR vs. Frequency (10mA Load)

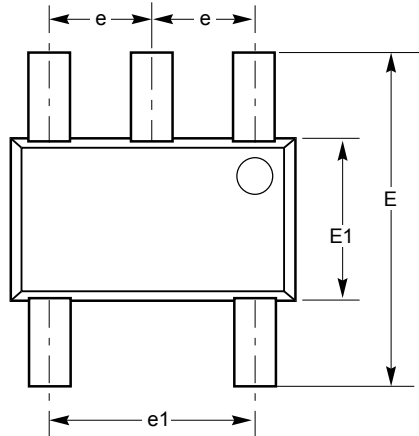


TRANSIENT CHARACTERISTICS (shown for 2.85V output option)

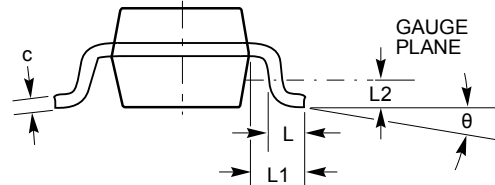
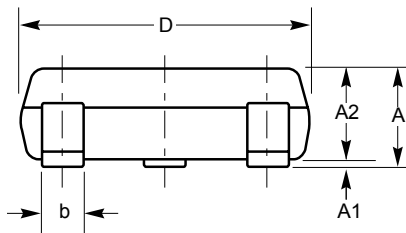
 $V_{IN} = 3.85V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1\mu F$, $C_{OUT} = 2.2\mu F$, $C_{BYP} = 10nF$, $T_A = 25^\circ C$ unless otherwise specified.

Line Transient Response (3.85V to 4.85V)

Load Transient Response (0.1mA to 500mA)


PACKAGE OUTLINES

5-LEAD TSOT-23



SYMBOL	MIN	NOM	MAX
A	—	—	1.00
A1	0.01	0.05	0.10
A2	0.80	0.87	0.90
b	0.30	—	0.45
c	0.12	0.15	0.20
D	2.90 BSC		
E	2.80 BSC		
E1	1.60 BSC		
e	0.95 BSC		
e1	1.90 BSC		
L	0.30	0.40	0.50
L1	0.60 REF		
L2	0.25 BSC		
θ	0°		8°



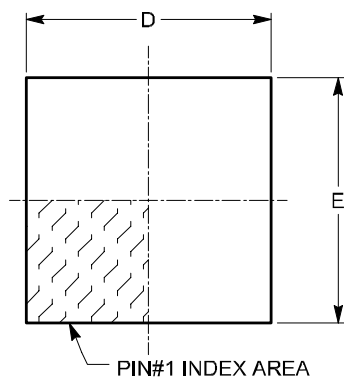
**For current Tape and Reel information, download the PDF file from:
<http://www.catsemi.com/documents/tapeandreel.pdf>.**

Notes:

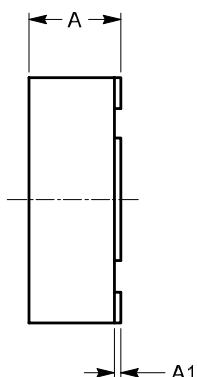
- (1) All dimensions are in millimeters, angles in degrees.
- (2) REFER JEDEC MO-193.

PACKAGE OUTLINES

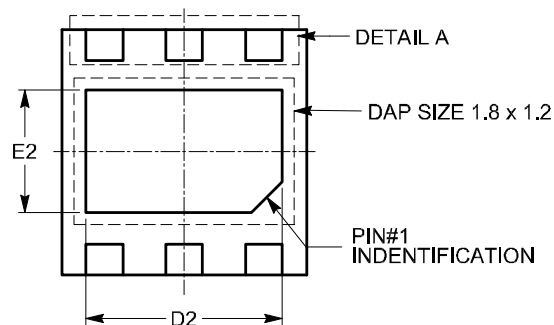
6-LEAD TDFN (2mm x 2mm)



TOP VIEW

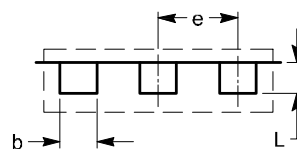


SIDE VIEW

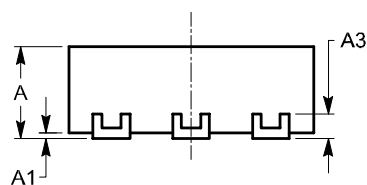


BOTTOM VIEW

SYMBOL	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3	0.20 REF		
b	0.25	0.30	0.35
D	1.90	2.00	2.10
D2	1.50	1.60	1.70
E	1.90	2.00	2.10
E2	0.90	1.00	1.10
e	0.65 TYP		
L	0.16	0.25	0.35



DETAIL A



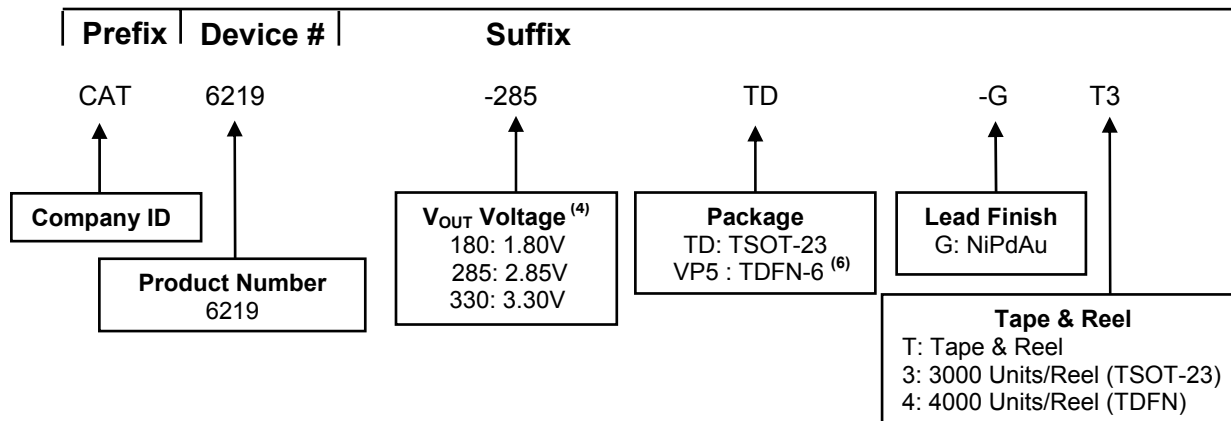
FRONT VIEW

For current Tape and Reel information, download the PDF file from:
<http://www.catsemi.com/documents/tapeandreel.pdf>.

Notes:

- (1) All dimensions are in millimeters, angles in degrees.
- (2) REFER JEDEC MO-229.

EXAMPLE OF ORDERING INFORMATION



Ordering Number	V _{OUT} Voltage ⁽⁵⁾	Package	Quantity per Reel
CAT6219-180TD-GT3	1.80V	TSOT-23	3000
CAT6219-285TD-GT3	2.85V	TSOT-23	3000
CAT6219-330TD-GT3	3.30V	TSOT-23	3000

Notes:

- (1) All packages are RoHS-compliant (Lead-free, Halogen-free).
- (2) The standard lead finish is NiPdAu pre-plated (PPF) lead frames.
- (3) The device used in the above example is a CAT6219-285TD-GT3 ($V_{OUT} = 2.85V$, in a TSOT-23 package, NiPdAu, Tape and Reel, 3000 units).
- (4) Standard voltages are 1.80V, 2.85V and 3.30V. For other voltage options, please contact your nearest Catalyst Semiconductor Sales office.
- (5) All output voltage options have the same marking.
- (6) Contact factory for availability.
- (7) Package Marking for CAT6219 family is "RV."

REVISION HISTORY

Date	Rev.	Reason
04/20/2007	A	Initial Release

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